

自主封測 品質把控 售後保障

WEB | WWW.TDSEMIC.COM



電源管理



顯示驅動



二三極管



LDO穩壓器



觸摸芯片



MOS管



運算放大器



存儲芯片



MCU



串口通信

DB107S-TD

產品規格說明書

DB101S thru DB107S

1.0 A Single-Phase Glass Passivated Bridge Rectifiers Rectifier Reverse Voltage 50 to 1000V

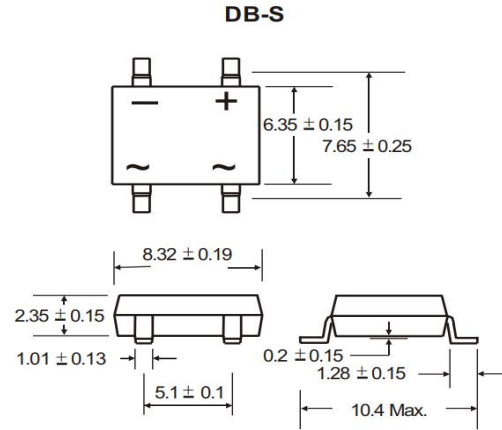


Features

- This series is UL listed under the Recognized Component Index, file number E142814
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- Surge overload ratings to 50 amperes
- Ideal for printed circuit board application
- High temperature soldering guaranteed 265 °C / 10 seconds at 5 lbs (2.3kg) tension

Mechanical Data

Case: Molded plastic
Terminals: Plated leads solderable per MIL-STD-202, Method 208
Polarity: Marked on body
Mounting Position: Any
Weight: 0.04 ounce, 1.0 grams (approx)



Maximum Ratings & Thermal Characteristics

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz.
For Capacitive load derate current by 20%.

Parameter	Symbol	DB101S	DB102S	DB103S	DB104S	DB105S	DB106S	DB107S	Unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at TA=40°C	IF(AV)	1.0							A
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM	50							A
Rating for fusing (t<8.3ms)	I ² t	10							A ² sec
Typical thermal resistance per element (1)	ReJA	110							°C / W
Typical junction capacitance per element (2)	Cj	25.0							pF
Operating junction and storage temperature range	TJ, TSTG	-55 to + 150							°C

Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz.
For Capacitive load derate by 20 %.

Parameter	Symbol	DB101S	DB102S	DB103S	DB104S	DB105S	DB106S	DB107S	Unit
Maximum instantaneous forward voltage drop per leg at 1.0A	VF	1.1							V
Maximum DC reverse current at rated TA =25°C DC blocking voltage per element TA =125°C	IR	10 500							μA

Notes: (1)Thermal resistance from Junction to Ambient on P.C.board mounting.
(2)Measured at 2.0MHz and applied reverse voltage of 4.0 volts.

Rating and Characteristic Curves ($T_A=25^{\circ}\text{C}$ Unless otherwise noted) DB101S thru DB107S

Fig. 1 Derating Curve for Output Rectified Current

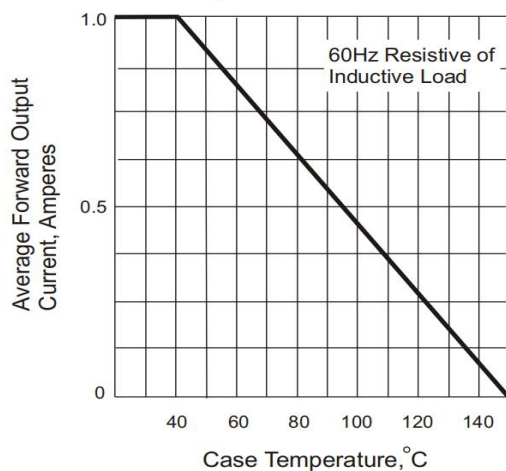


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

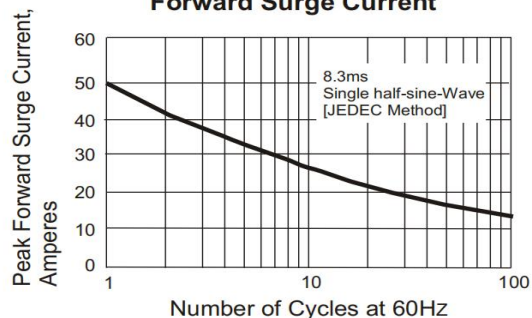


Fig. 4 Typical Revers Characteristics

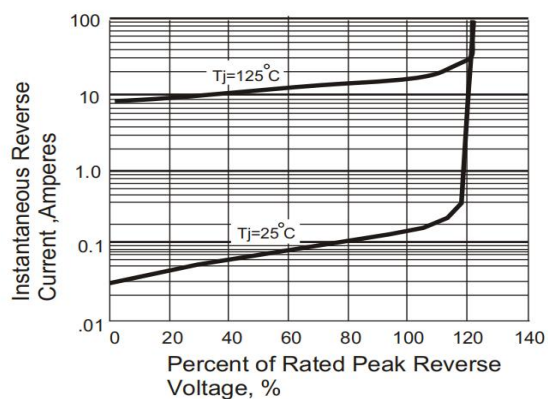


Fig. 3 Typical Instantaneous Forward Characteristics

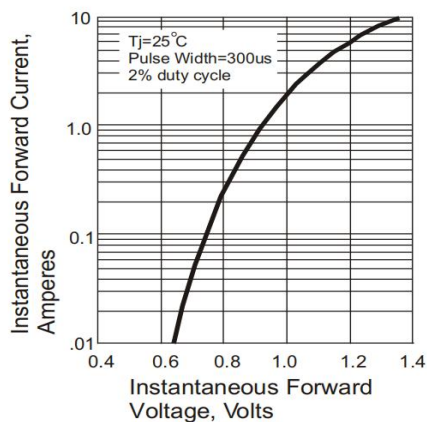


Fig. 5 Typical Junction Capacitance

